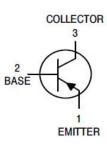


TO-92





Primary Characteristics				
BV _{CBO}	300V			
BV _{CEO}	300V			
BV _{EBO}	5V			
I _C	500mA			
Pc	625mW			
T _J	-50 ~ +150 °C			
T_{STG}	-50 ~ +150 °C			

Features

- Pb Free
- Major application: amplifying · switching



Mechanical Data

- Case: TO-92, Molded plastic
- Terminal: Pure tin plated, lead free

Maximum Rating (Ta=25°C unless otherwise noted)							
Parameter	Symbol	Testing Condition		Value	Unit		
Collector -Base Breakdown Voltage	BV _{CBO}	I _C =0.1mA	I _E =0	≧300	V		
Collector –Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA	I _B =0	≧300	٧		
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =0.1mA	I _C =0	≧5	٧		
Collector Cutoff Current	I _{CBO}	V _{CB} =200V	I _E =0	≦100	nA		
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V	I _C =0	≦100	nA		
Collector -Emitter Saturation Voltage	V _{CE(sat)}	I _C =20mA	I _B =2mA	≦0.5	V		
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C =20mA	I _B =2mA	≦0.9	V		
DC Current Gain	h _{FE}	V _{CE} =10V	I _C =10mA	≥40	-		
Current-Gain - Bandwidth Product	f _T	V _{CE} =20V	I _C =10mA	≧50	MHz		



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